



# SOT-23 BIPOLAR TRANSISTORS TRANSISTOR(NPN)

### **FEATURES**

\* Power dissipation Рсм:

0.15 W (Tamb=25°C)

\* Collector current Ісм:

0.2

\* Collector-base voltage

50 V<sub>(BR)</sub>CBO:

\* Operating and storage junction temperature range

T<sub>J</sub>,Tstg: -55°C to +150°C

#### **MECHANICAL DATA**

\* Case: Molded plastic

\* Epoxy: UL 94V-O rate flame retardant

\* Lead: MIL-STD-202E method 208C guaranteed

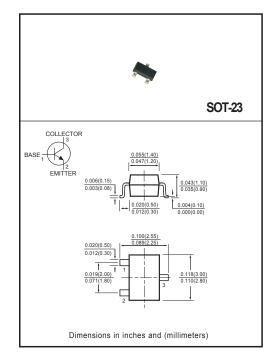
\* Mounting position: Any

\* Weight: 0.008 gram

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

### ELECTRICAL CHARACTERISTICS ( @ TA = 25°C unless otherwise noted )



CHARACTERISTICS	SYMBOL	MIN	MAX	UNITS
Collector-base breakdown voltage (I <sub>C</sub> = 100μA, I <sub>E</sub> =0)	V <sub>(BR)CBO</sub>	50	-	٧
Collector-emitter breakdown voltage (I <sub>C</sub> = 100μA, I <sub>B</sub> =0)	V <sub>(BR)CEO</sub>	50	-	٧
Emitter-base breakdown voltage (I <sub>E</sub> = 100μA, I <sub>C</sub> =0)	V <sub>(BR)EBO</sub>	6	-	V
Collector cut-off current (V <sub>CB</sub> = 50V, I <sub>E</sub> =0)	Ісво	-	0.1	μА
Emitter cut-off current (V <sub>EB</sub> = 6V, I <sub>C</sub> =0)	I <sub>EBO</sub>	-	0.1	μА
DC current gain (V <sub>CE</sub> = 6V, I <sub>C</sub> = 1mA)	h <sub>FE</sub>	150	800	-
DC current gain (V <sub>CE</sub> = 6V, I <sub>B</sub> = 0.1mA)	1175	50	-	-
Collector-emitter saturation voltage (I <sub>C</sub> = 100mA, I <sub>B</sub> = 10mA)	V <sub>CE(sat)</sub>	-	0.3	V
Base - emitter saturation voltage (I <sub>C</sub> = 100mA, I <sub>B</sub> = 10mA)	V <sub>BE(sat)</sub>	-	1	V
Transition frequency (V <sub>CE</sub> = 6V, I <sub>C</sub> = 10mA)	fT	180	-	MHz
Collector output capacitance (V <sub>CE</sub> = 6V, I <sub>E</sub> = 0, f= 1MHz)	Cob	-	4	pF
Noise figure (V <sub>CE</sub> = 6V, I <sub>E</sub> = -0.1mA, f= 1KHz, Rg=2K $\Omega$ )	NF	-	15	dB

## CLASSIFICATION OF hFE(1)

RANK	E	F	G
Range	150-300	250-500	400-800
Marking	LE	LF	LG

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